

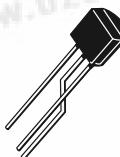
Silicon Controlled Rectifiers

PNPN devices designed for high volume, line-powered consumer applications such as relay and lamp drivers, small motor controls, gate drivers for larger thyristors, and sensing and detection circuits. Supplied in an inexpensive TO-226AA (TO-92) package which is readily adaptable for use in automatic insertion equipment.

- Sensitive Gate Trigger Current — 200 μ A Maximum
- Low Reverse and Forward Blocking Current — 100 μ A Maximum, $T_C = 125^\circ\text{C}$
- Low Holding Current — 5 mA Maximum
- Glass-Passivated Surface for Reliability and Uniformity

**BRY55-30*
thru 600***

SCRs
0.8 AMPERE RMS
30 TO 600 VOLTS



CASE 29-04
(TO-226AA)
STYLE 3
WITH TO-18 LEADFORM*

MAXIMUM RATINGS ($T_J = 25^\circ\text{C}$ unless otherwise noted.)

Rating	Symbol	Value	Unit
Peak Repetitive Forward and Reverse Blocking Voltage ⁽¹⁾ ($R_{GK} = 1000 \Omega$, $T_J = 25$ to 125°C) Marking: BRY55-1 ... BRY55-30 -2 ... BRY55-60 -3 ... BRY55-100 -4 ... BRY55-200 -6 ... BRY55-400 -7 ... BRY55-500 -8 ... BRY55-600	V_{RRM} , V_{DRM}		Volts
Forward Current RMS (All Conduction Angles)	$I_T(\text{RMS})$	0.8	Amp
Peak Forward Surge Current, $T_A = 25^\circ\text{C}$ (1/2 Cycle, Sine Wave, 60 Hz)	I_{TSM}	8	Amps
Circuit Fusing Considerations, $T_A = 25^\circ\text{C}$ ($t = 8.3$ ms)	I^2t	0.15	A^2s
Peak Gate Power — Forward, $T_A = 25^\circ\text{C}$	P_{GM}	0.1	Watt
Peak Gate Current Forward, $T_A = 25^\circ\text{C}$ (300 μ s, 120 PPS)	I_{GFM}	1	Amp
Peak Gate Voltage — Reverse	V_{GRM}	5	Volts
Operating Junction Temperature Range @ Rated V_{RRM} and V_{DRM}	T_J	-40 to +125	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-40 to +150	$^\circ\text{C}$
Lead Solder Temperature (< 1.5 mm from case, 10 s max.)		+230	$^\circ\text{C}$

*European part numbers only. Package is Case 29 with Leadform 18.

1. V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

BRY55-30 thru 600

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	75	°C/W
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	200	°C/W

ELECTRICAL CHARACTERISTICS (TC = 25°C, RGK = 1000 Ω unless otherwise noted.)

Characteristic	Symbol	Min	Max	Unit
Peak Forward Blocking Current (V _D = Rated V _{DRM} @ TC = 125°C)	I _{DRM}	—	100	μA
Peak Reverse Blocking Current (V _R = Rated V _{RRM} @ TC = 125°C)	I _{RRM}	—	100	μA
Forward "On" Voltage ⁽¹⁾ (I _{TM} = 1 A Peak @ TA = 25°C)	V _{TM}	—	1.7	Volts
Gate Trigger Current (Continuous dc) (Anode Voltage = 7 Vdc, R _L = 100 Ohms)	I _{GT}	—	200	μA
Gate Trigger Voltage (Continuous dc) (Anode Voltage = 7 Vdc, R _L = 100 Ohms) (Anode Voltage = Rated V _{DRM} , R _L = 100 Ohms)	V _{GT}	— — 0.1	0.8 1.2 —	Volts
Holding Current (Anode Voltage = 7 Vdc, initiating current = 20 mA)	I _H	— —	5 10	mA

1. Forward current applied for 1 ms maximum duration, duty cycle $\leq 1\%$.

2. RGK current is not included in measurement.

3. MARKING: BRY55-30 = BRY55-1

BRY55-60 = BRY55-2

BRY55-100 = BRY55-3

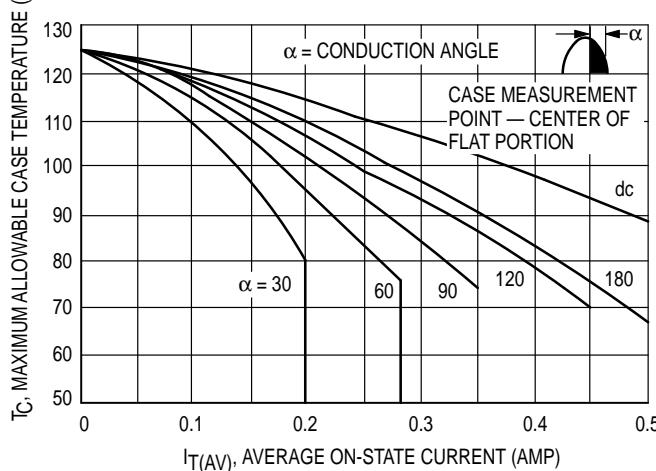
BRY55-200 = BRY55-4

BRY55-400 = BRY55-6

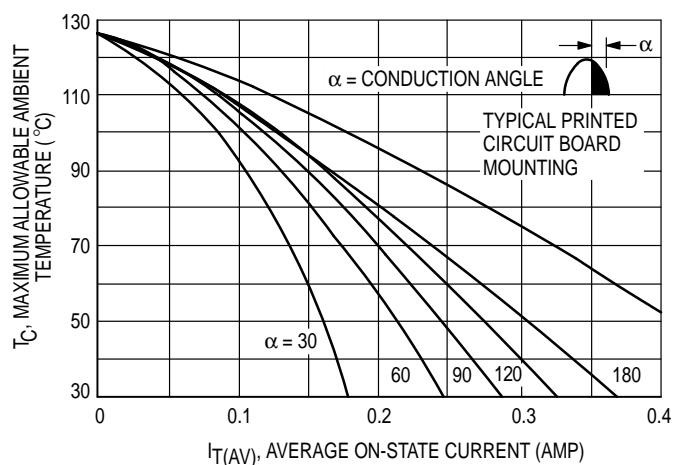
BRY55-500 = BRY55-7

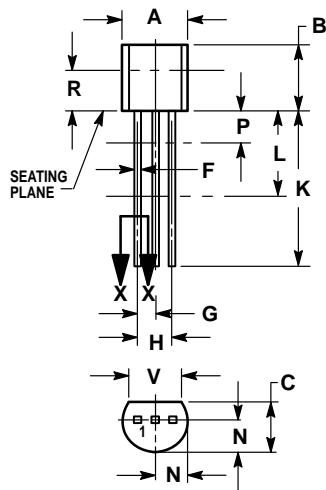
BRY55-600 = BRY55-8

**FIGURE 1 — CURRENT DERATING
(REFERENCE: CASE TEMPERATURE)**

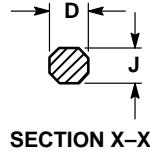


**FIGURE 2 — CURRENT DERATING
(REFERENCE: AMBIENT TEMPERATURE)**



PACKAGE DIMENSIONS

STYLE 3:
 1. ANODE
 2. ANODE
 3. CATHODE

**SECTION X-X****NOTES:**

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. DIMENSION F APPLIES BETWEEN P AND L. DIMENSION D AND J APPLY BETWEEN L AND K MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.022	0.41	0.55
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	—	12.70	—
L	0.250	—	6.35	—
N	0.080	0.105	2.04	2.66
P	—	0.100	—	2.54
R	0.115	—	2.93	—
V	0.135	—	3.43	—

**CASE 029-04
(TO-226AA)**

BRY55-30 thru 600

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